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## Ratiometric Linear Hall-effect Sensor OHN3150U, OHN3151U, OHS3150U, OHS3151U



### Features:

- Ratiometric linear output capable of sinking and sourcing current
- 4.5 V to 6.0 V operation
- Responds equally to positive and negative magnetic fields
- Excellent temperature stability to operate in harsh environments
- Robust package capable of withstanding harsh environments



### Description:

Each ratiometric linear Hall-effect sensor contains a monolithic integrated circuit on a single chip. This circuit incorporates a quadratic Hall sensing element, which minimizes the effects of mechanical and thermal stress on the Hall element and temperature compensating circuitry to compensate for the inherent Hall element sensitivity change over temperature current.

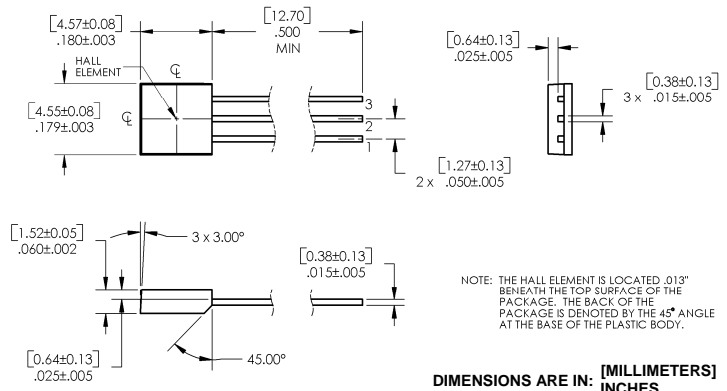
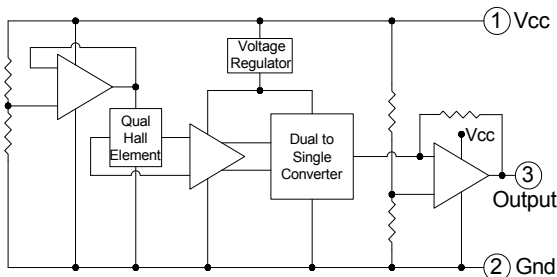
These ratiometric linear Hall-effect sensors provide an output voltage that varies in proportion to the applied magnetic field. The voltage output will increase in response to a south pole (positive) magnetic field applied perpendicular to the package symbolization face, and will decrease in response to a north pole (negative) magnetic field.

These 3150U & 3151U ratiometric linear Hall-effect sensors can be used as a non-contact sensor for rotary and linear position sensing and for current sensing. The devices in this series are similar in performance, except for their allowable quiescent voltage output change over the specified operating temperature range.

### Applications:

- Non-contact magnetic sensing
- Assembly line automation
- Machine automation
- Machine safety
- Door sensor
- Where sensing is required in dirty environments

Ordering Information		
Through Hole	Temp. Range	V <sub>0Q</sub> Threshold
OHN3150U	-20°C to +85°C	V <sub>0Q</sub> Change over T <sub>A</sub> = ±35 Gauss
OHS3150U	-40°C to +150°C	
OHN3151U	-20°C to +85°C	V <sub>0Q</sub> Change over T <sub>A</sub> = ±50 Gauss
OHS3151U	-40°C to +150°C	



RoHS

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## Ratiometric Linear Hall-effect Sensor Emitting Diode OHN3150U, OHN3151U, OHS3150U, OHS3151U



### Absolute Maximum Ratings

Supply Voltage, $V_{CC}$	6 V
Storage Temperature Range, $T_S$	-65°C to +170°C
Operating Temperature Range, $T_A$ (OHS prefix) (OHN prefix)	-40°C to +150°C -20°C to +85°C
Lead Soldering Temperature (1/8 inch [3.2 mm] from case for 5 seconds with soldering iron)	260°C <sup>(1)</sup>
Power Dissipation, $P_D$	100 mW
Output Current, $I_O$	5 mA
Magnetic Flux Density, B	Unlimited

### Electrical Characteristics (Over Operating Temperature Range at $V_{CC} = 5$ V, unless otherwise noted)

SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS
$V_{CC}$	Supply Voltage	4.5	5.0	6.00	V	
$I_{CC}$	Supply Current		5.5	10.00	mA	$V_{CC} = 6$ V, $I_O = 0$ mA, B = OG
$V_{OQ}$	Quiescent Voltage Output	2.25	2.5	2.75	V	B = OG, $T_A = 25^\circ$ C
		2.10	2.5	2.90	V	B = OG, $T_A = -40^\circ$ C to +150°C
$I_O$	Sink Current	0.5			mA	
$I_O$	Source Current	-1.0			mA	

SYMBOL	PARAMETER	OHS3150U			OHS3151U			OHN3150U			OHN3151U			UNITS
		MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
$T_A$	Operating Temperature Range	-40	-	150	-40	-	150	-20	-	85	-20	-	85	° C
Sens	Sensitivity @ $T_A = 25^\circ$ C over $T_A$	2.25 2.0	2.5 -	2.75 3.0	2.25 2.0	2.5 -	2.75 3.0	2.25 2.0	2.5 -	2.75 3.0	2.25 2.0	2.5 -	2.75 3.0	mV/G mV/G
$\Delta$ Sens( $\Delta$ T)	Sens Change @ $T_A > 25^\circ$ C @ $T_A < 25^\circ$ C	-2	-	8	-2	-	8	-2	-	8	-2	-	8	%
		-10	-	0	-10	-	0	-10	-	0	-10	-	0	%
$\Delta V_{OQ}(\Delta T)$	$V_{OQ}$ Change over $T_A$	-	-	±35	-	-	±50	-	-	±35	-	-	±50	G
$\Delta$ Sens( $\Delta$ V)	Ratiometric Sense Change	-	100	-	-	100	-	-	100	-	-	100	-	%
$\Delta V_{OQ}(\Delta V)$	Ratiometric $V_{OQ}$ Change	-	100	-	-	100	-	-	100	-	-	100	-	%
+Lin	Positive Lin $\geq 25$ < 25	99	-	105	99	-	105	99	-	105	99	-	105	%
		99	-	110	99	-	110	99	-	110	99	-	110	%
-Lin	Negative Lin $\geq 25$ < 25	95	-	101	95	-	101	95	-	101	95	-	101	%
		90	-	101	90	-	101	90	-	101	90	-	101	%
Sym	Output Symmetry	95	100	105	95	100	105	95	100	105	95	100	105	%

Note:

- (1) Negative current is defined as a coming out of (sourcing) the output.
- (2) See characteristics definitions for test conditions and calculation formulas.

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## Ratiometric Linear Hall-effect Sensor OHN3150U, OHN3151U, OHS3150U, OHS3151U



### Characteristics Definitions

**Quiescent voltage Output:** With no magnetic field present the device in the quiescent state and the voltage output is approximately equal to one-half the supply voltage ( $V_{OQ} = V_{CC} / 2$ ) over the operating voltage and temperature range. The change in quiescent voltage output over temperature gives the device's equivalent accuracy and is specified in gauss by the calculation.

$$\Delta V_{OQ (T)} = \frac{V_{OQ (TA)} - V_{OQ (25^{\circ}C)}}{Sens_{(25^{\circ}C)}}$$

**Sensitivity:** A magnetic south pole at, and perpendicular to, the device's symbolized package face will increase the voltage output above the quiescent value. Conversely a magnetic north pole will decrease the voltage output below the quiescent value. This change in voltage output with applied magnetic field is sensitivity and is specified in mV/G by the calculation.

$$Sens = \frac{V_{O (+500G)} - V_{O (-500G)}}{1000}$$

The change in sensitivity over temperature is specified in percent by the calculation

$$\Delta Sens_{(\Delta T)} = \frac{Sens_{(TA)} - Sens_{(25^{\circ}C)}}{Sens_{(25^{\circ}C)}} \times 100\%$$

**Ratiometry:** The quiescent voltage output and sensitivity of these ratiometric linear Hall-effect devices are proportional to the supply voltage. The change in quiescent voltage output with supply voltage is specified in percent by the calculation

$$\Delta V_{OQ (\Delta V)} = \frac{V_{O (VCC)} - V_{O (5V)}}{V_{CC} / 5 V} \times 100\%$$

This change in sensitivity with supply voltage is also specified in percent by the calculation

$$\Delta Sens_{(\Delta V)} = \frac{V_{OQ (VCC)} / V_{OQ (5V)}}{V_{CC} / 5 V} \times 100\%$$

**Linearity & Symmetry:** The ability of the voltage output to vary in constant proportion to the applied magnetic field is linearity and is specified in percent by the calculation

$$+ \text{ Linearity} = \frac{V_{O (+500G)} - V_{OQ}}{2(V_{O (250G)} - V_{OQ})} \times 100\%$$

$$- \text{ Linearity} = \frac{V_{O (-500G)} - V_{OQ}}{2(V_{O (-250G)} - V_{OQ})} \times 100\%$$

The output is also specified in percent by the calculation

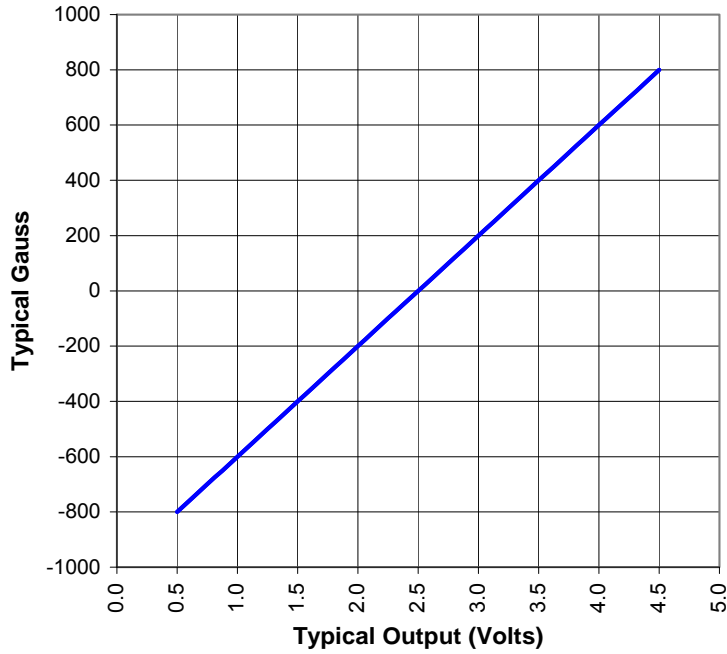
$$- \text{ Linearity} = \frac{V_{O (500G)} - V_{OQ}}{V_{OQ} - V_{OQ (-500G)}} \times 100\%$$

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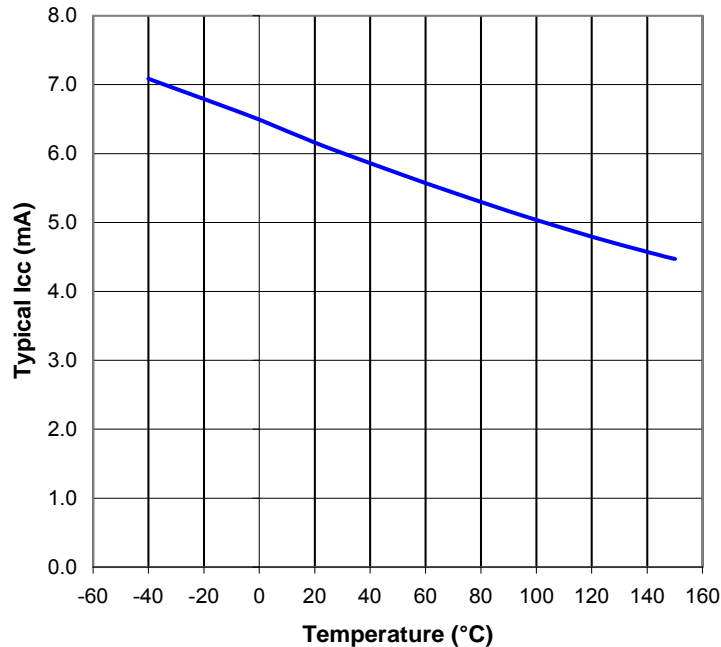
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**Output vs Gauss**



**Icc vs Temperature**



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